

MBRD620CT, MBRD630CT, MBRD640CT, MBRD650CT, MBRD660CT

MBRD620CT, MBRD640CT and MBRD660CT are Preferred Devices

SWITCHMODE™ Power Rectifiers

DPAK Surface Mount Package

... in switching power supplies, inverters and as free wheeling diodes, these state-of-the-art devices have the following features:

- Extremely Fast Switching
- Extremely Low Forward Drop
- Platinum Barrier with Avalanche Guardrings

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 0.4 gram (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 75 units per plastic tube
- Available in 16 mm Tape and Reel, 2500 units per reel, by adding a "T4" suffix to the part number
- Marking: B620T, B630T, B640T, B650T, B660T

MAXIMUM RATINGS

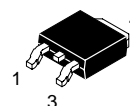
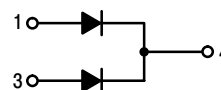
Please See the Table on the Following Page



ON Semiconductor™

<http://onsemi.com>

SCHOTTKY BARRIER RECTIFIERS 6.0 AMPERES 20 TO 60 VOLTS



DPAK
CASE 369A
PLASTIC

MARKING DIAGRAM



B6x0T = Device Code
x = 2, 3, 4, 5 or 6

ORDERING INFORMATION

Device	Package	Shipping
MBRD620CTT4	DPAK	2500/Tape & Reel
MBRD630CTT4	DPAK	2500/Tape & Reel
MBRD640CTT4	DPAK	2500/Tape & Reel
MBRD650CT	DPAK	75 Units/Rail
MBRD650CTT4	DPAK	2500/Tape & Reel
MBRD660CT	DPAK	75 Units/Rail
MBRD660CTRL	DPAK	1800/Tape & Reel
MBRD660CTT4	DPAK	2500/Tape & Reel

Preferred devices are recommended choices for future use and best overall value.

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MAXIMUM RATINGS

Rating	Symbol	MBRD					Unit
		620CT	630CT	640CT	650CT	660CT	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	20	30	40	50	60	Volts
Average Rectified Forward Current $T_C = 130^\circ\text{C}$ (Rated V_R)	Per Diode Per Device $I_{F(AV)}$	3 6					Amps
Peak Repetitive Forward Current, $T_C = 130^\circ\text{C}$ (Rated V_R , Square Wave, 20 kHz) Per Diode	I_{FRM}	6					Amps
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I_{FSM}	75					Amps
Peak Repetitive Reverse Surge Current (2 μs , 1 kHz)	I_{RRM}	1					Amp
Operating Junction Temperature	T_J	-65 to +150					$^\circ\text{C}$
Storage Temperature	T_{stg}	-65 to +175					$^\circ\text{C}$
Voltage Rate of Change (Rated V_R)	dv/dt	10,000					$\text{V}/\mu\text{s}$

THERMAL CHARACTERISTICS PER DIODE

Maximum Thermal Resistance, Junction to Case	$R_{\theta JC}$	6	$^\circ\text{C}/\text{W}$
Maximum Thermal Resistance, Junction to Ambient (Note 1.)	$R_{\theta JA}$	80	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS PER DIODE

Maximum Instantaneous Forward Voltage (Note 2.) $i_F = 3$ Amps, $T_C = 25^\circ\text{C}$ $i_F = 3$ Amps, $T_C = 125^\circ\text{C}$ $i_F = 6$ Amps, $T_C = 25^\circ\text{C}$ $i_F = 6$ Amps, $T_C = 125^\circ\text{C}$	V_F	0.7 0.65 0.9 0.85	Volts
Maximum Instantaneous Reverse Current (Note 2.) (Rated dc Voltage, $T_C = 25^\circ\text{C}$) (Rated dc Voltage, $T_C = 125^\circ\text{C}$)	i_R	0.1 15	mA

1. Rating applies when surface mounted on the minimum pad size recommended.
2. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$.

TYPICAL CHARACTERISTICS

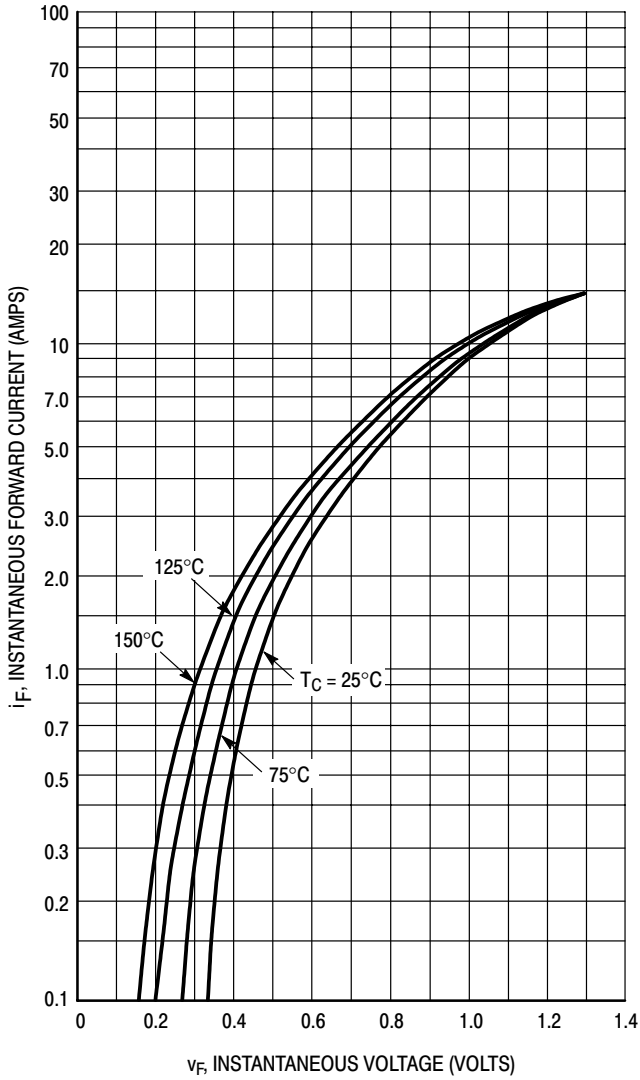
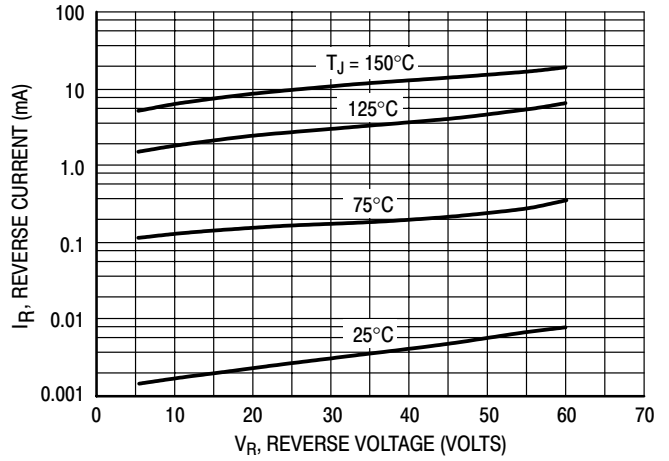


Figure 1. Typical Forward Voltage, Per Leg



*The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these curves if V_R is sufficient below rated V_R .

Figure 2. Typical Reverse Current, * Per Leg

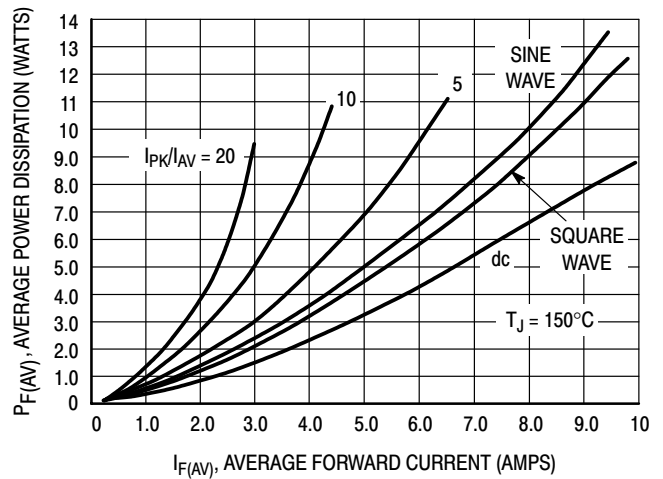


Figure 3. Average Power Dissipation, Per Leg

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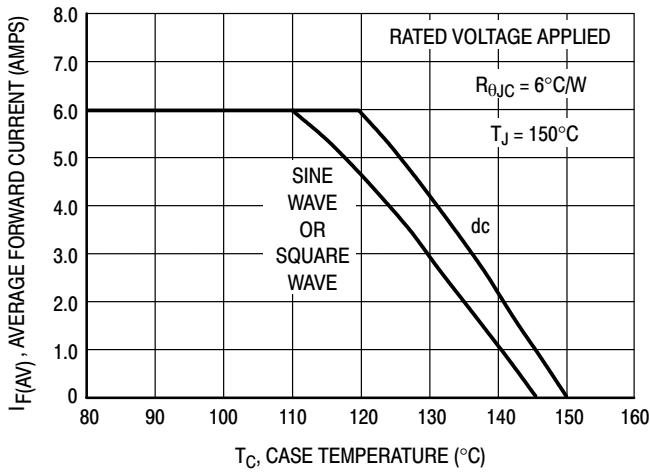


Figure 4. Current Derating, Case, Per Leg

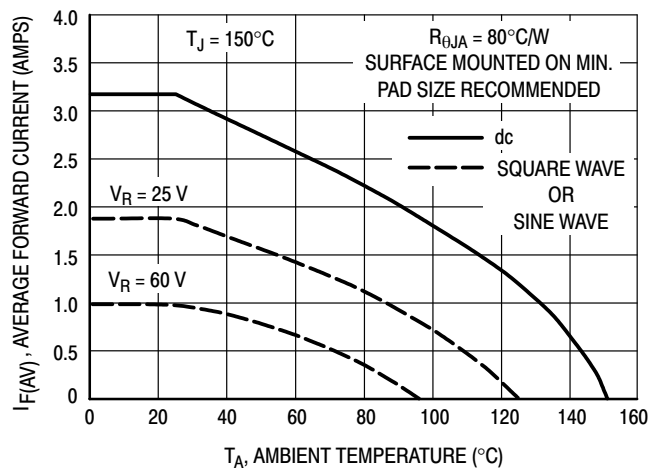


Figure 5. Current Derating, Ambient, Per Leg

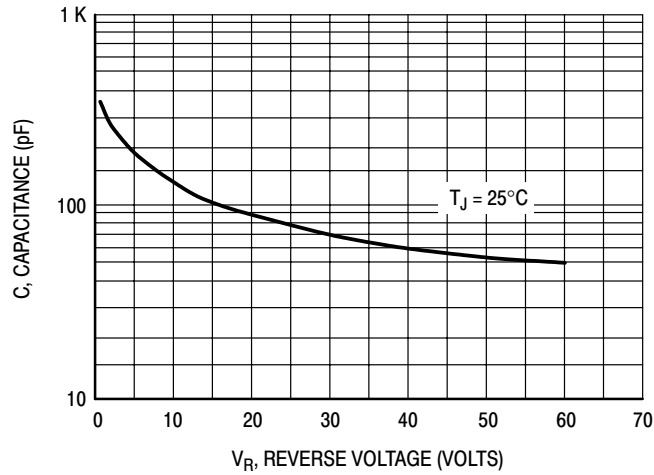
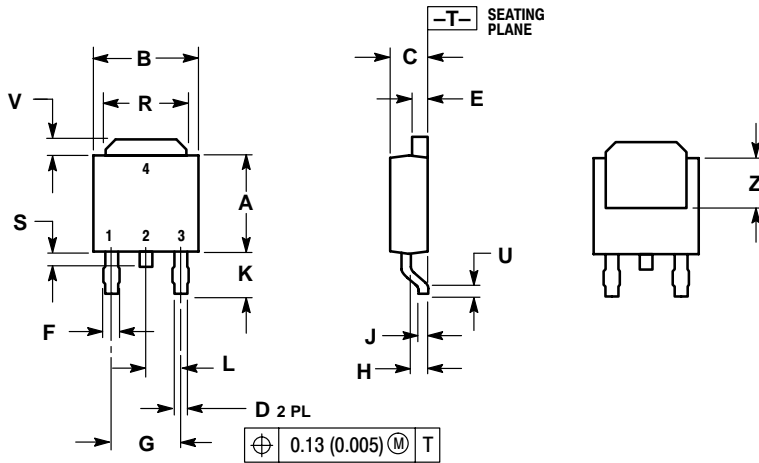


Figure 6. Typical Capacitance, Per Leg

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PACKAGE DIMENSIONS

DPAK
 PLASTIC
 CASE 369A-13
 ISSUE AA



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.250	5.97	6.35
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.033	0.040	0.84	1.01
F	0.037	0.047	0.94	1.19
G	0.180 BSC		4.58 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.175	0.215	4.45	5.46
S	0.020	0.050	0.51	1.27
U	0.020	---	0.51	---
V	0.030	0.050	0.77	1.27
Z	0.138	---	3.51	---

Notes

Notes

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